**NANOS Hall Sensor** 

# **SH-44C**

Nanos Co., Ltd.

# **InSb Hall Sensor**

#### Shipped in bulk (800pcs per pack)

Notice : Please check the important points on the back of this catalog when reviewing this product.

#### Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Maximum Input Current	Imax	20 (at 25°C)	mA
Operating Temp. Range	Topr	-40 ~ +120	°C
Storage Temp. Range	Tstg	-40 ~ +150	°C

#### Marking (by Laser)



#### Rank (by Output Hall Voltage)

Output Hall Voltage	Rank	Conditions
196 ~ 236	D	
228 ~ 274	E	Vin=1V, B=50mT
266 ~ 320	F	(Constant Voltage)
-	-	

#### Dimension Drawing (Unit : mm)



This product is not guaranteed or intended to be used for highly reliable purposes, such as medical, aerospace, transport, traffic signal, combustion, nuclear control, and various safety devices, in which failure or malfunction of the equipment is usually expected to cause serious damage to life, body, property, etc. Therefore, please do not use this product for these purposes unless otherwise authorized by us in writing. In the unlikely event that this product is used for these purposes, we shall not be liable for any damages arising from such use.



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#### Electrical Specifications

Parameter	Symbol	Conditions Min.		Max.	Unit
Output Hall Voltage	Vh	Vin=1V, B=50mT 19		320	mV
Input Resistance	Rin	Ic=0.1mA, B=0mT	240	550	Ω
Output Resistance	Rout	Ic=0.1mA, B=0mT	240	550	Ω
Offset Voltage	Vo	Vin=1V, B=0mT	√in=1V, B=0mT -7		mV
Temp. Coeff. Of Vh	αVh	Avg. on 0~40°C, B=50mT, I=5mA	Тур1.8		%/°C
Temp. Coeff. Of Rin, Rout	αRin	Avg. on 0~40°C, B=0mT, I=0.1mA	Тур1.8		%/°C

#### ※ Note.

1) Vh = Vhm - Vo (Vhm : measured at 50mT)

2)	αVh =	$\frac{1}{Vh(T_1)}$	X	$\frac{Vh(T_3) - Vh(T_2)}{(T_3 - T_2)} \ 2$	<b>x</b> 100%
3)	αRin =	$\frac{1}{\text{Rin}(T_1)}$	х	$\frac{\operatorname{Rin}(T_3) - \operatorname{Rin}(T_2)}{(T_3 - T_2)}$	<b>X</b> 100%

4)  $T_1 = 20^{\circ}C$ ,  $T_2 = 0^{\circ}C$ ,  $T_3 = 40^{\circ}C$ 

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**Characteristic Curves** 



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#### **IMPORTANT NOTICE**

1) Our products described in this document (hereinafter referred to as "Product") and the specifications of this product are subject to change without notice to improve this product. Therefore, please check with your sales representative or our dealership representative to ensure that the information contained in this document is up-to-date.

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4) While we strive to improve quality and reliability, electronics can generally malfunction or fail. If you use this product, it is your responsibility to design the safety necessary for your product so that life, body, property, etc. are not compromised due to malfunction or failure of this product.

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